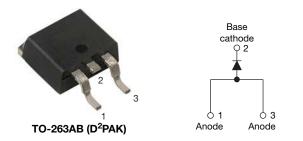
Vishay Semiconductors

# High Voltage Surface Mount Input Rectifier Diode, 10 A



PRODUCT SUMMARY							
Package	TO-263AB (D <sup>2</sup> PAK)						
I <sub>F(AV)</sub>	10 A						
V <sub>R</sub>	800 V, 1000 V, 1200 V						
V <sub>F</sub> at I <sub>F</sub>	1.1 V						
I <sub>FSM</sub>	160 A						
T <sub>j</sub> max.	150 °C						
Diode variation	Single die						

## FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according to JEDEC-JESD47
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **APPLICATIONS**

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

## DESCRIPTION

The VS-10ETS..SPbF rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS							
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS				
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	12.0	16.0	А				

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Sinusoidal waveform	10	A						
V <sub>RRM</sub>		800/1200	V						
I <sub>FSM</sub>		160	A						
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.1	V						
TJ		- 40 to 150	°C						

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-10ETS08SPbF	800	900							
VS-10ETS10SPbF	1000	1100	0.5						
VS-10ETS12SPbF	1200	1300							

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	$T_{C}$ = 105 °C, 180° conduction half sine wave	10						
Maximum peak one cycle	l	10 ms sine pulse, rated $V_{RRM}$ applied	135	А					
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	ns sine pulse, no voltage reapplied 160						
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	91	A <sup>2</sup> s					
Maximum Futor fusing	1-1	10 ms sine pulse, no voltage reapplied	130	A-5					
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1290	A²√s					

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS			
Maximum forward voltage drop	V <sub>FM</sub>	10 A, T <sub>J</sub> = 25 °C	1.1	V				
Forward slope resistance	r <sub>t</sub>	T.I = 150 °C	20	mΩ				
Threshold voltage	V <sub>F(TO)</sub>	1J = 150 C	0.82	V				
Maximum reverse lookage ourrent	I <sub>RM</sub>	$T_J = 25 \ ^\circ C$	V <sub>B</sub> = Rated V <sub>BBM</sub>	0.05	mA			
Maximum reverse leakage current		T <sub>J</sub> = 150 °C	VR = naleu VRRM	0.50	ШA			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 150	°C				
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5	°C/W				
Maximum thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> <sup>(1)</sup>		62	0/10				
Soldering temperature	Τ <sub>S</sub>		260	°C				
Approximate weight			2	g				
Approximate weight			0.07	oz.				
			10ET	S08S				
Marking device		Case style D <sup>2</sup> PAK (SMD-220)	10ETS10S					
			10ETS12S					

## Note

(1) When mounted on 1" square (650 mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994



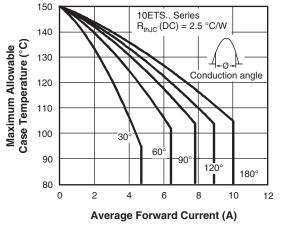


Fig. 1 - Current Rating Characteristics

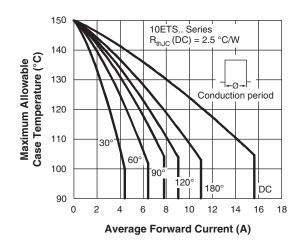


Fig. 2 - Current Rating Characteristics

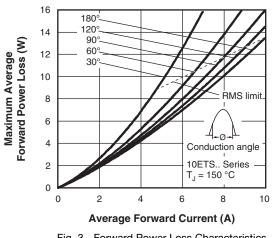
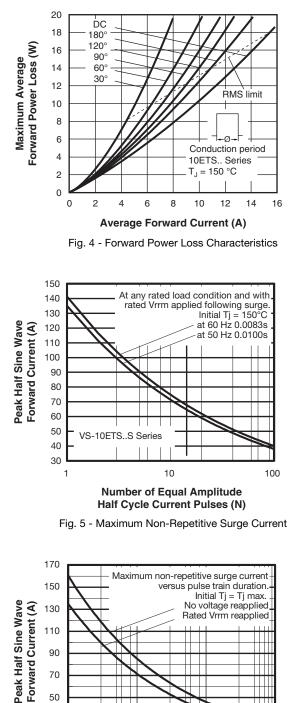


Fig. 3 - Forward Power Loss Characteristics

# VS-10ETS..SPbF Series

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50 30 VS-10ETS..S Series 10 0.01 0.1 1 10 Pulse Train Duration (s)

Fig. 6 - Maximum Non-Repetitive Surge Current

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# **VS-10ETS..SPbF Series**

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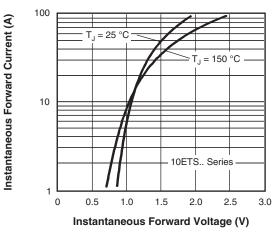


Fig. 7 - Forward Voltage Drop Characteristics

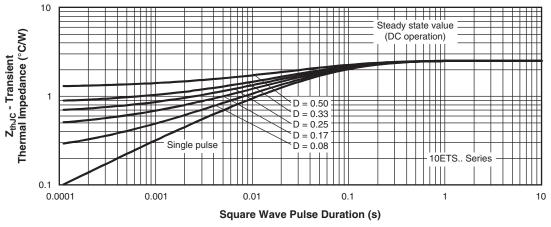


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

7 8 9	- • None = Tube • TRL = Tape and reel • TRR = Tape and reel	<ul> <li>TRL = Tape and reel (left oriented)</li> <li>TRR = Tape and reel (right oriented)</li> </ul>				
ORDERING INFORMAT	ION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-10ETS08SPbF	50	1000	Antistatic plastic tube			
VS-10ETS08STRRPbF	800	800	13" diameter reel			



# Vishay Semiconductors

**VS-10ETS..SPbF Series** 

## **ORDERING INFORMATION TABLE**

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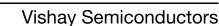
Device code	VS-	10	Е	т	S	12	S	TRL	PbF
	1	2	3	4	5	6	7	8	9
	1 2 3	- Cur - Circ	rent rati	nicondul ng (10 = iguratior	10 A)	duct			
	4	- Pac	– Single kage: = TO-22						
	5		e of silio = Stanc	con: lard reco	overy re	ctifier	Г	00 - 00	
	6 7	- Volt	age coo	le x 100 ) D <sup>2</sup> PAK	= V <sub>RRM</sub>	1		08 = 80 10 = 10 12 = 12	00 V
	8	• TI		ube pe and i ipe and			-		
	9			(Pb)-fre			- /		
RING INFORM	ATION	(Examp	ole)						

LINKS TO RELATED DOCUMENTS								
VS-10ETS08SPbF	50	1000	Antistatic plastic tube					
VS-10ETS12STRLPbF	800	800	13" diameter reel					
VS-10ETS12STRRPbF	800	800	13" diameter reel					
VS-10ETS12SPbF	50	1000	Antistatic plastic tube					
VS-10ETS10STRLPbF	800	800 13" dia						
VS-10ETS10STRRPbF	800	800 13" diamete						
VS-10ETS10SPbF	50	1000	Antistatic plastic tube					
VS-10ETS08STRLPbF	800	800	13" diameter reel					
VS-10ETS08STRRPbF	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					

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# **Outline Dimensions**

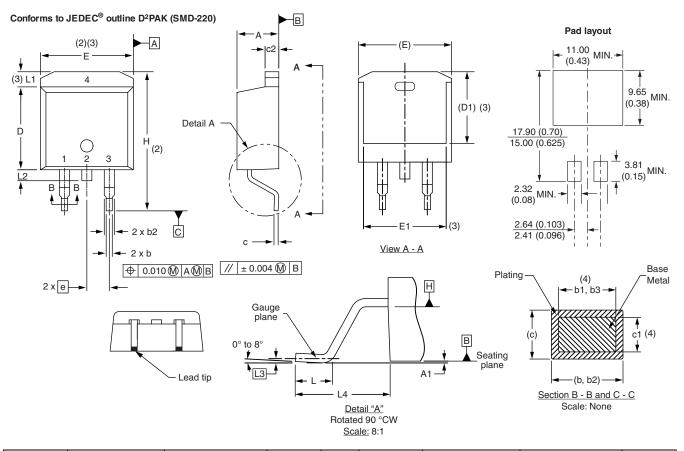


D<sup>2</sup>PAK

## **DIMENSIONS** in millimeters and inches

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SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

<sup>(2)</sup> Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

<sup>(3)</sup> Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inch

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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